

GRF2013

Broadband Linear Gain Block 0.05 to 8.0 GHz



Features

Reference: 5V/90mA/1.9 GHz

Gain: 18.5 dBOIP3: 38.5 dBmOP1dB: 22.5 dBm

NF: 1.3 dB

Reference: 8V/100mA/1.9 GHz

Gain: 18.5 dBOIP3: 41.0 dBmOP1dB: 25.3 dBm

NF: 1.4 dB

Low Noise Figure

Flat Gain

Flexible Biasing

• Internally Matched to 50 Ω

Process: GaAs pHEMT

Applications

Linear Driver Amplifier

Small Cells and Cellular Repeaters

IF Amplifier

Wireless Backhaul

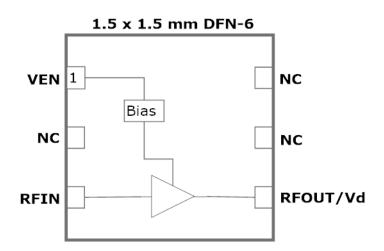
Product Description

GRF2013 is a broadband gain block with low noise figure and high linearity designed for small cell, wireless infrastructure and other high performance applications. It exhibits outstanding broadband NF, linearity and return losses over 0.7 to 3.8 GHz with a single match.

Optimizing the bias inductor and coupling caps for lower frequency operation will yield strong performance down to 50 MHz. For applications above 4 GHz, the addition of simple external matching yields outstanding linearity and gain performance up to 8 GHz.

The device is operated from a supply voltage of 2.7 to 8.0V with a selectable Iddq range of 15 to 100 mA for optimal efficiency and linearity.

Consult with the GRF applications engineering team for custom tuning/evaluation board data. De-embedded sparameters are available on the website landing page for the device.





GRF2013

Broadband Linear Gain Block 0.05 to 8.0 GHz

Absolute Ratings:

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{DD}	0	9.0	V
RF Input Power: (Load VSWR < 2:1; V _D : <= 8.0 volts)	P _{IN MAX}		22	dBm
Operating Temperature (Package Heat Sink)	T_AMB	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P _{DISS MAX}		1.0	W
Electrostatic Discharge:				
Charged Device Model:	CDM	1500		V
Human Body Model:	НВМ	250		V
Storage:				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	



Caution! ESD Sensitive Device



Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2013 landing page: Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification:

Link to manufacturing note

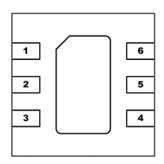
Revision Date: 06/10/19



GRF2013

Broadband Linear Gain Block 0.05 to 8.0 GHz

Pin Out (Top View)



Pin Assignments:

Revision Date: 06/10/19

Pin	Name	Description	Note
1	VENABLE	Enable Voltage Input	$\label{eq:Venable} \mbox{Venable and series resistor set $Iddots$. Venable < 0.2 volts disables device. Ondie pull-down resistor will turn the part off if this node is allowed to float.}$
2	NC	No Connect or Ground	No internal connection to die
3	RF_In	LNA RF input	Internally matched $50\Omega.$ An external DC blocking cap must be used.
4	RF_Out	LNA RF output	Internally matched $50\Omega.~V_{DD}$ must be applied through a choke to this pin
5	NC	No Connect or Ground	No internal connection to die
6	NC	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



GRF2013

Broadband Linear Gain Block 0.05 to 8.0 GHz

Nominal Operating Parameters:

Parameter	Symbol	Specification		Unit	Condition		
Parameter	Symbol	Min.	Тур.	Max.	Ullit	Condition	
Test Frequency	F _{TEST}		1.9		GHz	$V_{DD} = 5.0 \text{ V}, T_A = 25 ^{\circ}\text{C}$	
Gain	S21	17.5	18.5		dB		
Evaluation Board Noise Figure	NF		1.3	1.5	dB		
Output 3rd Order Intercept	OIP3		38.5		dBm	$4.0~\text{dBm}$ P_{OUT} per tone (1899 and 1901 MHz)	
Output 1dB Compression Power	OP1dB	21.0	22.5		dBm		
Switching Rise Time	T _{RISE}		500		ns		
Switching Fall Time	T _{FALL}		500		ns		
Supply Current	I _{DD}		90.0		mA		
Enable Current	IENABLE		5.0		mA		
Disabled Mode							
Leakage Current	ILEAKAGE		100		uA	VDD: 5.0V; VENABLE: 0.0V	
Thermal Data							
Thermal Resistance: (Infra-Red Scan)	Q jc		52		°C/W	On standard Evaluation Board	
Channel Temperature @ +85 C Reference (Package heat sink)	TCHANNEL		109 (See note)		°C	V _{DD} : 5.0 V; I _{DDQ} : 90 mA; No RF; P _{DISS} : 450 mW	

Note: MTTF >10^6 hours for Tchannel < 170 degrees C.

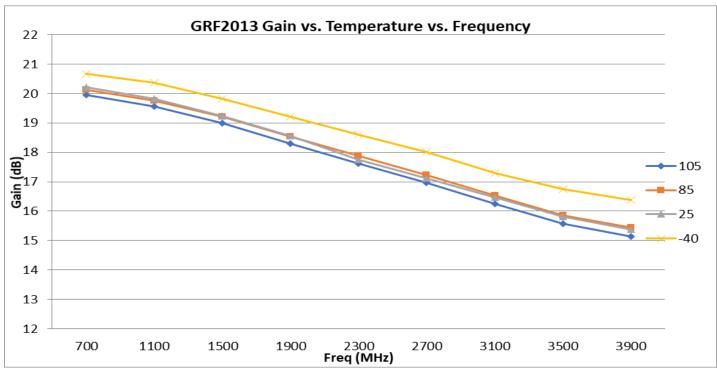
Revision Date: 06/10/19

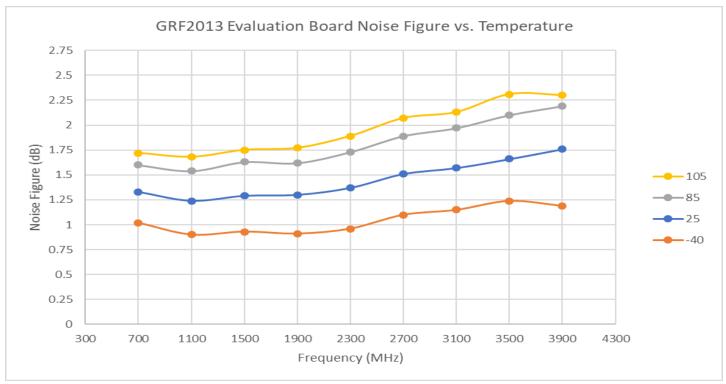




Broadband Linear Gain Block 0.05 to 8.0 GHz

GRF2013 Evaluation Board Measured Data: (0.7 to 3.8 GHz Tune)





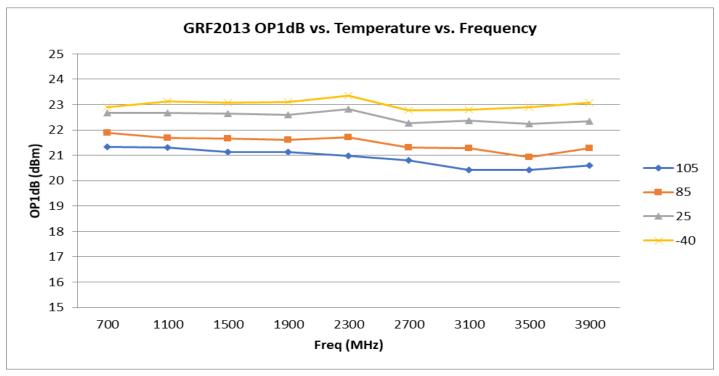


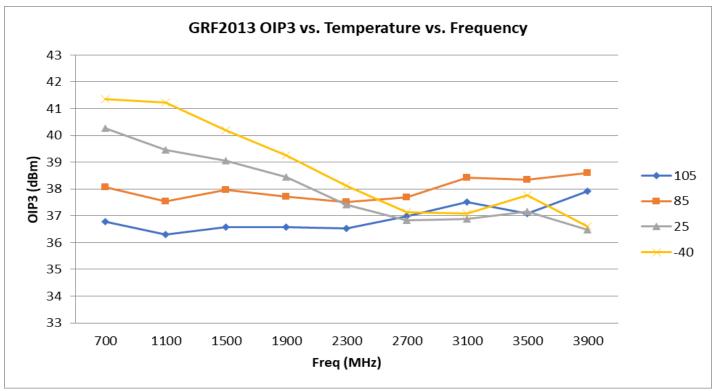


Released

Broadband Linear Gain Block 0.05 to 8.0 GHz

GRF2013 Evaluation Board Data: (0.7 to 3.8 GHz Tune)





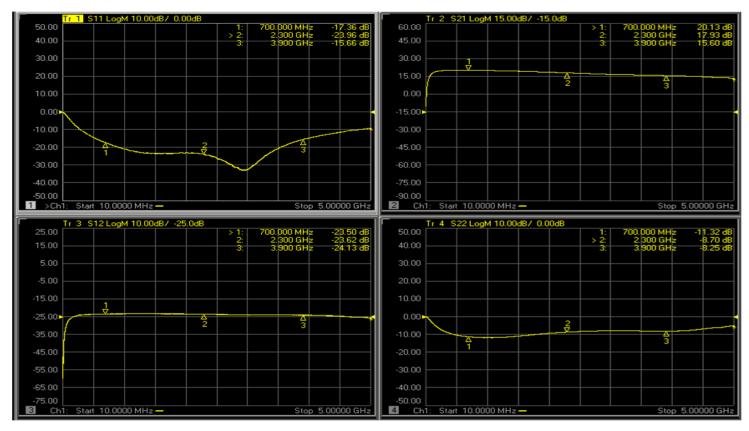
Guerrilla RE Proprietary Information, Guerrilla RETM and the composite logo of Guerrilla RETM are trademarks of Guerrilla RE. Inc. @2014 Guerrilla RE. Inc. All rights reserved

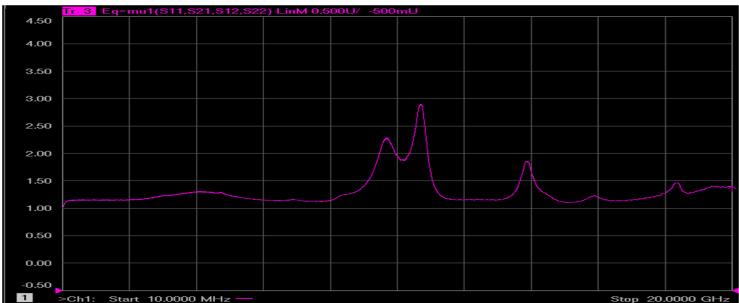




Broadband Linear Gain Block 0.05 to 8.0 GHz

GRF2013 Evaluation Board S-Pars and Stability Mu Factor: (0.7 to 3.8 GHz Tune)



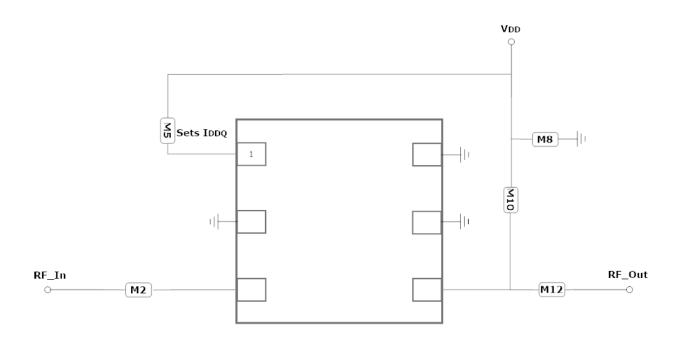


Note: Mu factor >= 1.0 implies unconditional stability.

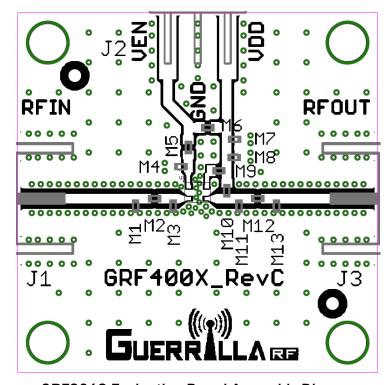




Broadband Linear Gain Block 0.05 to 8.0 GHz



GRF2013 Application Schematic



GRF2013 Evaluation Board Assembly Diagram



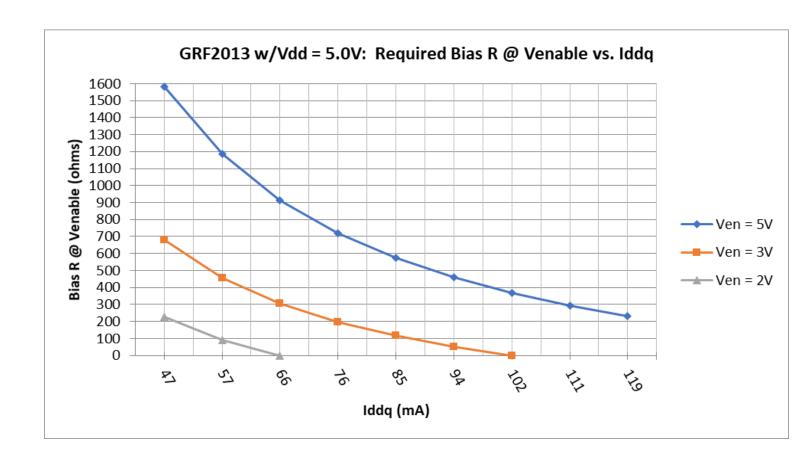
Released

GRF2013

Broadband Linear Gain Block 0.05 to 8.0 GHz

GRF2013 Standard Evaluation Board BOM: (0.7 to 3.8 GHz Tune)

Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M2	Capacitor	Murata	GRM	100 pF	0402	ok
M5 (See curves)	Resistor	Various	5%	Sets Iddq	0402	ok
M8	Capacitor	Murata	GRM	0.1 uF	0402	ok
M10	Inductor	Various	MLC	33 nH	0402	ok
M12	Capacitor	Murata	GRM	100 pF	0402	ok
Evaluation Board	GRF400X_RevC					

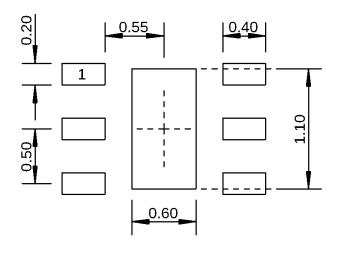






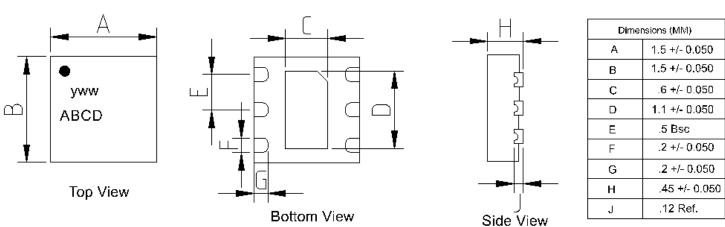
Released

Broadband Linear Gain Block 0.05 to 8.0 GHz



Dimensions in millimeters

1.5 mm DFN-6 Suggested PCB Footprint (Top View)



Dimensions (MM)		
Α	1.5 +/- 0.050	
В	1.5 +/- 0.050	
Ç	.6 +/- 0.050	
D	1.1 +/- 0.050	
E	.5 Bsc	
F	.2 +/- 0.050	
G	.2 +/- 0.050	
Н	.45 +/- 0.050	
٦	.12 Ref.	

1.5 mm DFN-6 Package Dimensions



GRF2013

Broadband Linear Gain Block 0.05 to 8.0 GHz

Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

Revision Date: 06/10/19

This datasheet, including the information contained in it, is provided by Guerrilla RF as a service to its customers and may be used for informational purposes only by the customer. Guerrilla RF assumes no responsibility for errors or omissions on this datasheet or the information contained herein. Information provided is believed to be accurate and reliable, however, no responsibility is assumed by Guerrilla RF for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. Guerrilla RF assumes no liability for any datasheet information, materials, products, product information, or other information provided hereunder, including the sale, distribution, reproduction or use of Guerrilla RF products, information or materials.

No license, whether express, implied, by estoppel, by implication or otherwise is granted by this datasheet for any intellectual property of Guerrilla RF, or any third party, including without limitation, patents, patent rights, copyrights, trademarks and trade secrets. All rights are reserved by Guerrilla RF.

All information herein, products, product information, datasheets, and datasheet information are subject to change and availability without notice. Guerrilla RF reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice. Guerrilla RF may further change its datasheet, product information, documentation, products, services, specifications or product descriptions at any time, without notice. Guerrilla RF makes no commitment to update any materials or information and shall have no responsibility whatsoever for conflicts, incompatibilities, or other difficulties arising from any future changes.

GUERRILLA RF INFORMATION, PRODUCTS, PRODUCT INFORMATION, DATASHEETS AND DATASHEET INFORMATION ARE PROVIDED "AS IS" AND WITHOUT WAR-RANTY OF ANY KIND, WHETHER EXPRESS, IMPLIED, STATUTORY, OR OTHERWISE, INCLUDING FITNESS FOR A PARTICULAR PURPOSE OR USE, MERCHANTABILITY, PERFORMANCE, QUALITY OR NON-INFRINGEMENT OF ANY INTELLECTUAL PROPERTY RIGHT; ALL SUCH WARRANTIES ARE HEREBY EXPRESSLY DISCLAIMED. GUERRILLA RF DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. GUERRILLA RF SHALL NOT BE LIABLE FOR ANY DAMAGES, INCLUDING BUT NOT LIMITED TO ANY SPECIAL, INDIRECT, INCIDENTAL, STATUTORY, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS THAT MAY RESULT FROM THE USE OF THE MATERIALS OR INFORMATION, WHETHER OR NOT THE RECIPIENT OF MATERIALS HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGE.

Customers are solely responsible for their use of Guerrilla RF products in the Customer's products and applications or in ways which deviate from Guerrilla RF's published specifications, either intentionally or as a result of design defects, errors, or operation of products outside of published parameters or design specifications. Customers should include design and operating safeguards to minimize these and other risks. Guerrilla RF assumes no liability or responsibility for applications assistance, customer product design, or damage to any equipment resulting from the use of Guerrilla RF products outside of stated published specifications or parameters.

Guerrilla RF Proprietary Information. Guerrilla RF™ and the composite logo of Guerrilla RF™ are trademarks of Guerrilla RF, Inc. ©2014 Guerrilla RF, Inc. All rights reserved.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Amplifier category:

Click to view products by Guerrilla RF manufacturer:

Other Similar products are found below:

A82-1 BGA622H6820XTSA1 BGA 728L7 E6327 BGB719N7ESDE6327XTMA1 HMC397-SX HMC405 HMC561-SX HMC8120-SX HMC8121-SX HMC-ALH382-SX HMC-ALH476-SX SE2433T-R SMA3101-TL-E SMA39 A66-1 A66-3 A67-1 A81-2 LX5535LQ LX5540LL MAAM02350 HMC3653LP3BETR HMC549MS8GETR HMC576-SX HMC-ALH435-SX SMA101 SMA32 SMA411 SMA531 SST12LP19E-QX6E WPM0510A HMC5879LS7TR HMC1087F10 HMC1086 HMC1016 SMA1212 MAX2689EWS+T MAAMSS0041TR MAAM37000-A1G LTC6430AIUF-15#PBF SMA70-2 SMA4011 A231 HMC-AUH232 LX5511LQ LX5511LQ-TR HMC7441-SX HMC-ALH310 XD1001-BD-000V A4011